

INFORMATION DISCLOSURE CITATION
BY APPLICANT
(USE SEVERAL SHEETS IF NECESSARY)

APPLICANT:

Emmanuel Hadji et al.

FILING DATE:

October 6, 2000

GROUP ART
UNIT:

1765

U.S. PATENT DOCUMENTS

Examiner Initial		Document No.	Date	Name	Class	Subclass	Filing Date If Appropriate
SA	A	5,363,398	11/1994	Glass et al.	372	92	
SA	B	5,374,564	12/1994	Bruel -	437	24	
	C						
	D						
	E						
	F						
	G						
	H						

FOREIGN PATENT DOCUMENTS

		Document No.	Date	Country	Class	Subclass	Translation
SA	I	0 578 407	1/1994	European			English text
	J						
	K						

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

SA	L	Yukari Ishikawa et al. EPITAXY-READY Si/SiO ₂ BRAGG REFLECTORS BY MULTIPLE SEPARATION-BY-IMPLANTED-OXYGEN. 16 December 1996. Pgs. 3881-3883.
	M	E. F. Schubert et al. GIANT ENHANCEMENT OF LUMINESCENCE INTENSITY IN Er-DOPED Si/SiO ₂ RESONANT CAVITIES. 21 September 1992. Pgs. 1381-1383.
	N	R. A. Soref et al. SILICON INTERSUBBAND LASERS. 1998. Pgs. 427-439.
	O	Richard A. Soref. PROSPECTS FOR NOVEL Si-BASED OPTOELECTRONIC DEVICES: UNIPOLAR AND p-i-p-i lasers. July 1992. Pgs 325-329.
	P	Michio Tajima et al. LUMINESCENCE DUE TO ELECTRON-HOLE CONDENSATION IN SILICON-ON-INSULATOR. August 1998. Pgs. 2224-2228.
SA	Q	M. Tajima et al. CHARACTERIZATION OF BOND AND ETCH-BACK SILICON-ON-INSULATOR WAFERS BY PHOTOLUMINESCENCE UNDER ULTRAVIOLET EXCITATION. January 1997. Pgs. 231-233.

Examiner:

Shamim Ahmed

Date Considered

8/14/02

*Examiner:

Initial if reference considered, regardless of whether citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.